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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
09/677,545	10/02/2000	Schrems Martin	GR 99 P 4724	3079	
, 7 ,	590 12/19/2002				
LERNER AND GREENBERG, P.A.			EXAMINER		
Post Office Box Hollywood, FL			NGUYEN, CUONG QUANG		
			ART UNIT	PAPER NUMBER	
			2811		

DATE MAILED: 12/19/2002

Please find below and/or attached an Office communication concerning this application or proceeding.

`		Application No.	Applicant(s)	<i>\</i>		
•	•			/		
Office Action Summary		09/677,545	MARTIN ET AL.			
	Office Action Summary	Examiner	Art Unit			
	- The MAILING DATE of this communication app	Cuong Q Nguyen	2811	ross		
Period fo	The state of the s	ears on the cover sheet with the c	orrespondence addi			
THE N - Exten after S - If the - If NO - Failur - Any re	DRTENED STATUTORY PERIOD FOR REPLY MAILING DATE OF THIS COMMUNICATION. sions of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a reply period for reply is specified above, the maximum statutory period we to reply within the set or extended period for reply will, by statute, apply received by the Office later than three months after the mailing dipatent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be timed within the statutory minimum of thirty (30) days will apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this corr O (35 U.S.C. § 133).	nmunication.		
1)	Responsive to communication(s) filed on					
2a)⊠	•	is action is non-final.				
3)	Since this application is in condition for allowa		osecution as to the	merits is		
, —	closed in accordance with the practice under					
•	on of Claims	•				
,—	Claim(s) <u>1 and 3-19</u> is/are pending in the appl					
	4a) Of the above claim(s) <u>10-19</u> is/are withdraw	n from consideration.				
· _	Claim(s) is/are allowed.					
· _	Claim(s) 1 and 3-9 is/are rejected.					
<u> </u>	Claim(s) is/are objected to.	I I'				
,—	Claim(s) are subject to restriction and/o on Papers	r election requirement.				
• •	The specification is objected to by the Examine	r				
•	•		miner.			
10) The drawing(s) filed on is/are: a) accepted or b) objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).						
11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner.						
If approved, corrected drawings are required in reply to this Office action.						
12) The oath or declaration is objected to by the Examiner.						
Priority under 35 U.S.C. §§ 119 and 120						
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).						
a) ☐ All b) ☐ Some * c) ☐ None of:						
1. Certified copies of the priority documents have been received.						
	2. Certified copies of the priority documents have been received in Application No					
* 8	3. Copies of the certified copies of the prior application from the International Busee the attached detailed Office action for a list	reau (PCT Rule 17.2(a)).		Stage		
14) 🗌 A	cknowledgment is made of a claim for domesti	c priority under 35 U.S.C. § 119(e) (to a provisional a	application).		
a) ☐ The translation of the foreign language provisional application has been received. 15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.						
Attachment	t(s)					
2) Notic	e of References Cited (PTO-892) e of Draftsperson's Patent Drawing Review (PTO-948) nation Disclosure Statement(s) (PTO-1449) Paper No(s) _	5) Notice of Informal	y (PTO-413) Paper No(s Patent Application (PTO			
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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 1, 3 and 9 are rejected under 35 U.S.C. 103(a) as being unpatentable over Arnold (US 5,937,296) in view of Nishimura (US 4,949,138) and further in view of Economikos et al. (US 6,180,480).

Regarding claim 1, Arnold discloses a trench capacitor structure comprising: a substrate (12) having a trench formed therein, wherein the trench having an upper portion and a lower portion; an insulation collar (50, 58) formed in upper portion of the trench; a buried well (16) formed in the substrate, wherein the lower portion of the trench extending partly through the buried well; a capacitor dielectric layer (34, a silicon oxide or a silicon nitride layer) lining the lower region of the trench; and a conductive trench filling (32) formed in the trench. See Arnold's Fig.1.

Arnold does not teach that the capacitor dielectric layer (34) can be formed of tungsten oxide and the conductive trench filling formed of tungsten-containing material disposed in upper and lower regions of the trench.

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Nishimura discloses a capacitor structure comprising a capacitor dielectric layer (15) is formed of silicon oxide, silicon nitride or tungsten oxide. See Nishimura's Fig.4 and col.2, lines 22-68.

Economikos et al. discloses a trench capacitor structure comprising a tungstencontaining material (30, 56) filled an upper region and a lower region of a trench to form a storage node of the trench capacitor. See Economikos et al.'s Fig.6.

It would have been obvious to one of ordinary skill in the art to form the capacitor dielectric layer of tungsten oxide instead of silicon nitride or silicon oxide as taught by Nishimura because these material are art recognized material for forming the capacitor dielectric layer and they are interchangeable. Moreover, one of ordinary skill in the art would have been motivated to do so because tungsten oxide has a very high dielectric constant comparing with silicon oxide or silicon nitride. It also would have been obvious to one of ordinary skill in the art to incorporate tungsten-containing filling material for forming the capacitor storage node as taught by Economikos et al. into Arnold's device in order to obtain a capacitor trench with completely filled conductive material. See Economikos et al.'s col.2, lines 23-30.

Regarding claim 3, the device formed by the combination of Arnold and Nishimura has capacitor dielectric layer of tungsten oxide which is the same material as claimed device. Therefore, the tungsten oxide capacitor dielectric layer in the device formed by

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the combination of Arnold and Nishimura inherently has a dielectric constant greater 50 as claimed.

Regarding claim 9, as shown in Arnold's Fig.9, a vertical transistor formed in the trench.

Claims 4-8 are rejected under 35 U.S.C. 103(a) as being unpatentable over Arnold in view of Nishimura, Economikos et al. and further in view of Wallace et al. (US 6,277,681).

Arnold, Nishimura and Economikos et al. substantially teach all the limitations of claims 1, 3, and 9 as shown above but fails to teach that barrier layers formed between the capacitor dielectric layer and the capacitor electrodes.

Wallace et al. discloses a capacitor structure (col.1, lines 20-23) comprising silicon nitride barrier layer (13, 17) formed between the high dielectric constant layer (15) and conductive layers. See Wallace et al.'s Fig.2.

It would have been obvious to one of ordinary skill in the art to incorporate the barrier layers as taught by Wallace et al. into the device formed by the combination of Arnold, Nishimura and Economikos et al. in order to dopants in the conductive layers diffusing into the dielectric layer. See Wallace et al.'s col.3 lines 15-20.

Response to Arguments

2. Applicant's arguments with respect to claims 1, 3-9 have been considered but are most in view of the new ground(s) of rejection.

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Conclusion

3. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

4. Papers related to this application may be submitted to Technology center (TC) 2800 by facsimile transmission. Papers should be faxed to TC 2800 via the TC 2800 Fax center located in Crystal Plaza 4, room 4-C23. The faxing of such papers must conform with the notice published in the Official Gazette, 1096 OG 30 (November 15, 1989). The Group 2811 Fax Center number is (703) 308-7722 and 308-7724. The Group 2811 Fax Center is to be used only for papers related to Group 2811 applications.

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Any inquiry concerning this communication or any earlier communication from 5. the Examiner should be directed to CUONG Q NGUYEN whose telephone number is

(703) 308-1293. The Examiner is in the Office generally between the hours of 6:30 AM

to 5:00 PM (Eastern Standard Time) Monday through Thursday.

. If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor TOM THOMAS who can be reached on (703) 308-2772. The fax phone

number for the organization where this application or proceeding is assigned is (703)

308-7722 or 308-7724.

Any inquiry of a general nature or relating to the status of this application should

be directed to the Technology Center Receptionists whose telephone number is 308-

0956.

Cuong Nguyen

December 9, 2002